



HAICHUANG SEMI

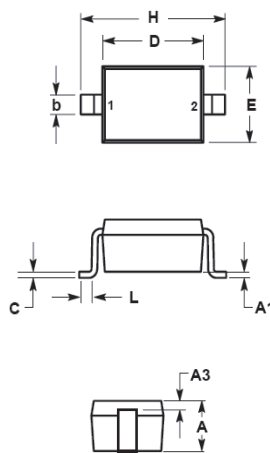
B5817WS/B5818WS/B5819WS

40V/1A SCHOTTKY BARRIER DIODE

Features

- Low Forward Voltage Drop.
- Surface Mounted Device.
- Pb free and RoHS compliant.

DEVICE	MARKING
B5817WS	SJ
B5818WS	SK
B5819WS	SL



SOD-323		
Dim.	Min.	Max.
A	0.80	1.10
A1	0.00	0.10
A3	0.15 REF	
B	0.25	0.40
C	0.10	0.15
D	1.60	1.80
E	1.15	1.35
L	0.20	0.50
H	2.30	2.80
Dimensions in millimeter		

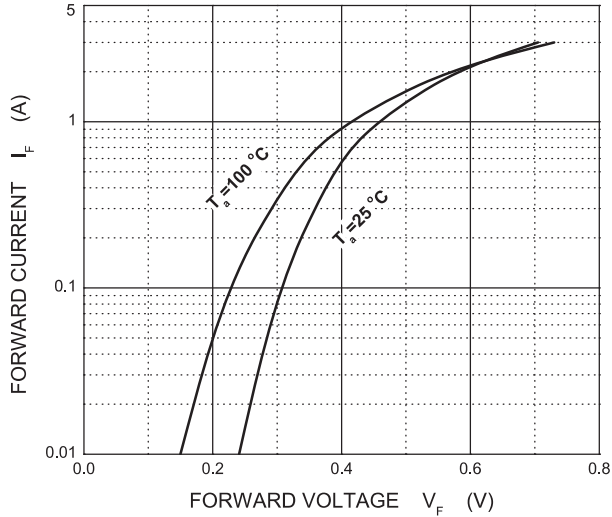
Maximum Ratings @ T_A = 25°C unless otherwise specified

Parameters	Symbol	B5817WS	B5818WS	B5819WS	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	V
Maximum RMS voltage	V _{RMS}	14	21	28	V
Maximum DC blocking voltage	V _{DC}	20	30	40	V
Maximum average forward rectified current	I _{FM}	1.0			A
Peak forward surge current 8.3 ms single half sine-wave	I _{FSM}	9			A
Typical thermal resistance	R _{θJA}	400			°C/W
Power Dissipation	PD	250			mW
Operating junction temperature	T _j	125			°C
Storage temperature range	T _{STG}	-50-+150			°C

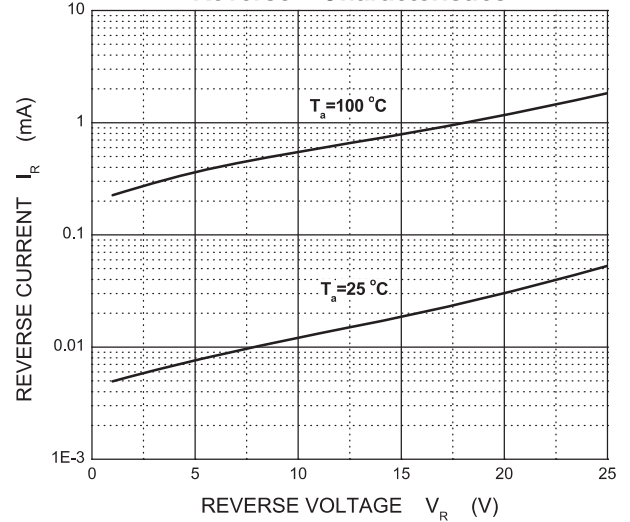
Electrical Characteristics @ T_A = 25°C unless otherwise specified

Parameters	Symbol	Test conditions	B5817WS	B5818WS	B5819WS	Unit
Maximum forward voltage	V _F	I _F = 1.0A I _F = 3.0A	0.450 0.750	0.550 0.875	0.600 0.900	V
Maximum reverse breakdown voltage	V _R	I _R =1mA	20	30	40	V
Maximum reverse current	I _R	V _R =20V B5817WS V _R =30V B5818WS V _R =40V B5819WS	1.0			mA
Type junction capacitance	C _j	V _R = 4.0V, f = 1MHz	120			pF

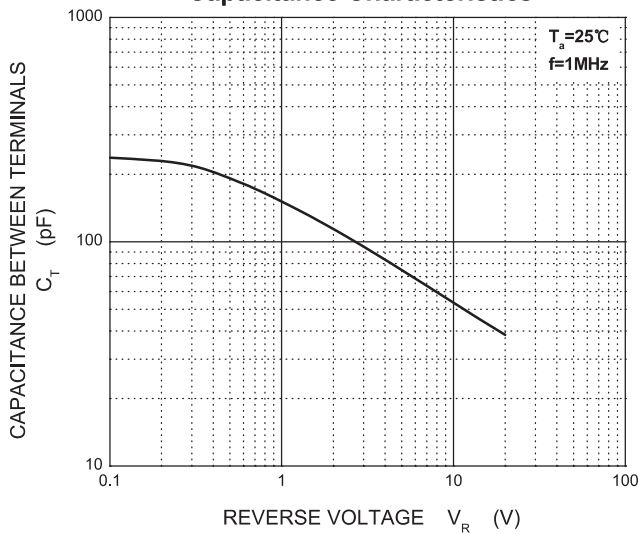
Forward Characteristics



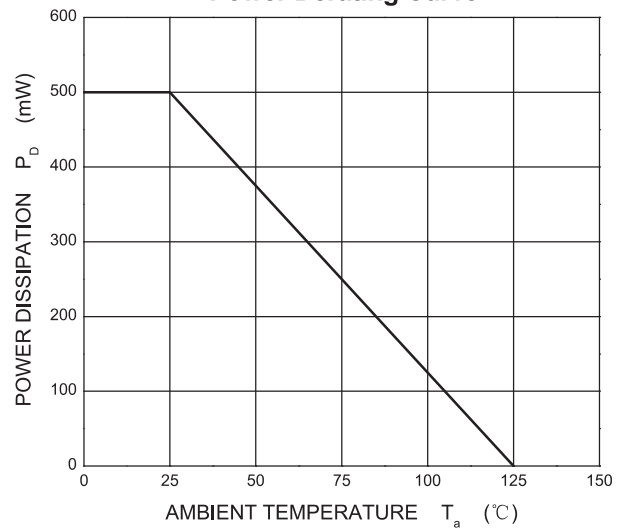
Reverse Characteristics



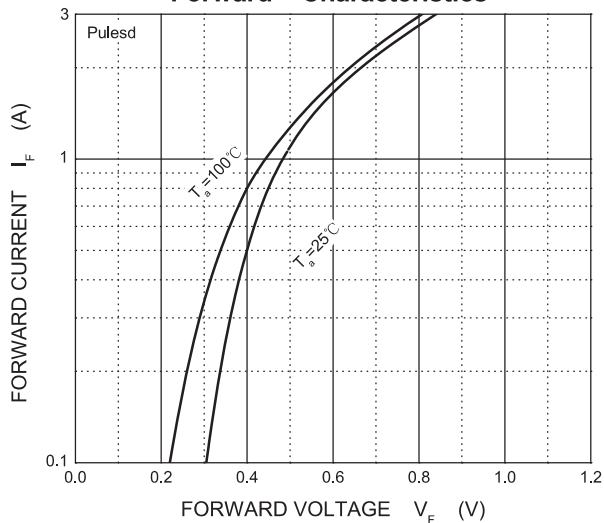
Capacitance Characteristics



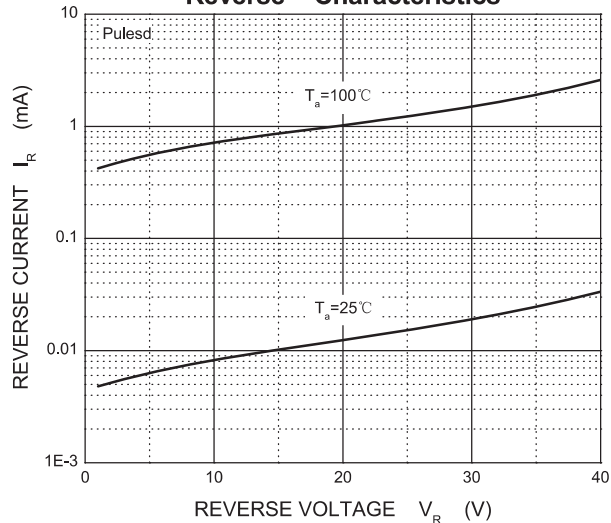
Power Derating Curve



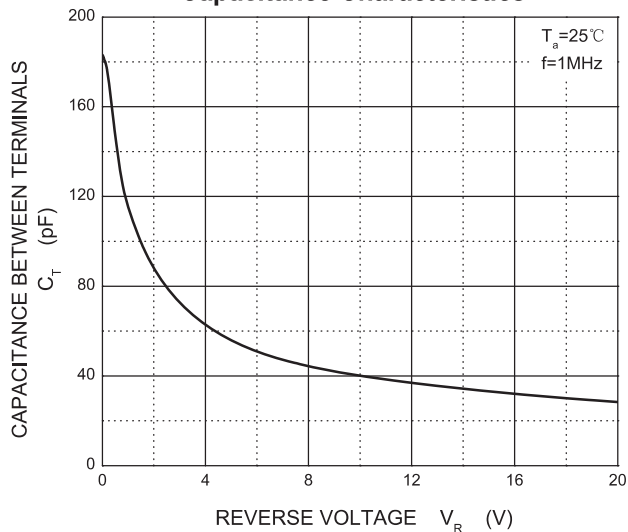
Forward Characteristics



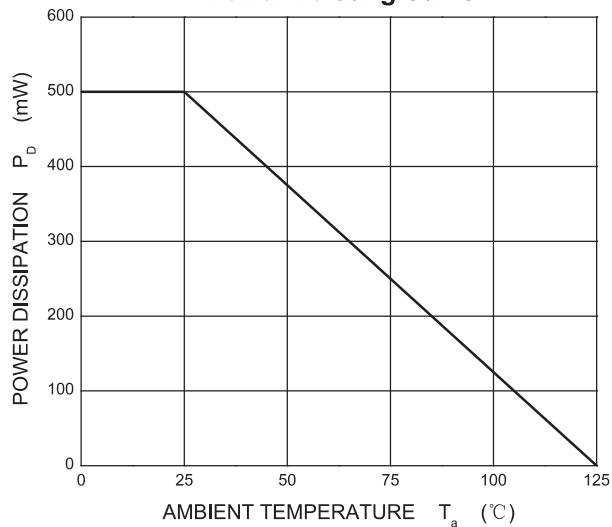
Reverse Characteristics

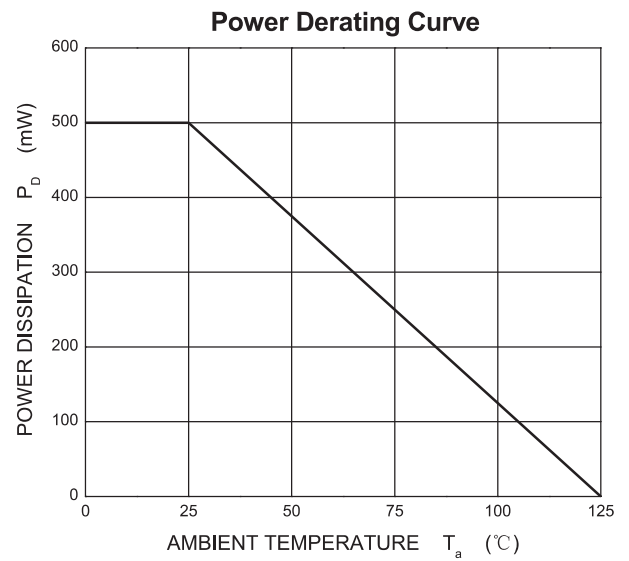
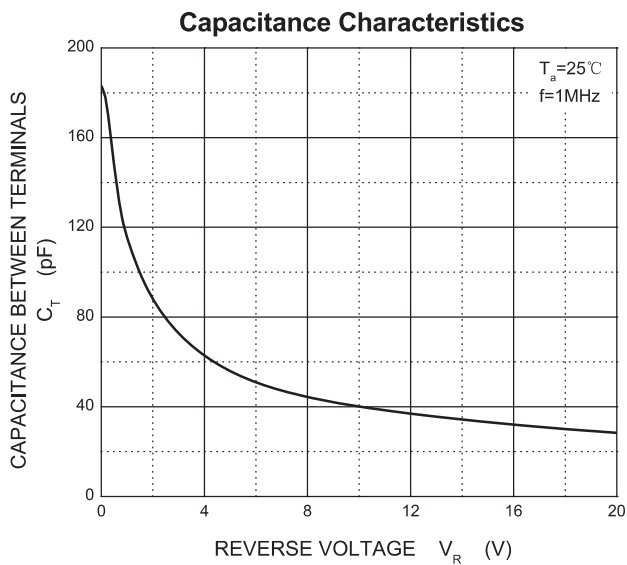
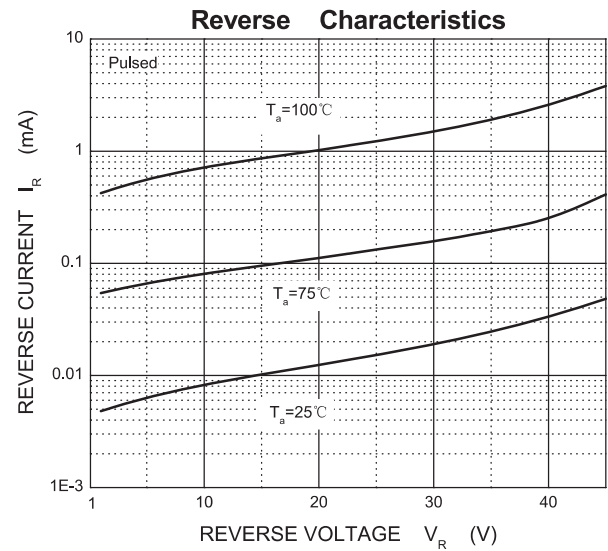
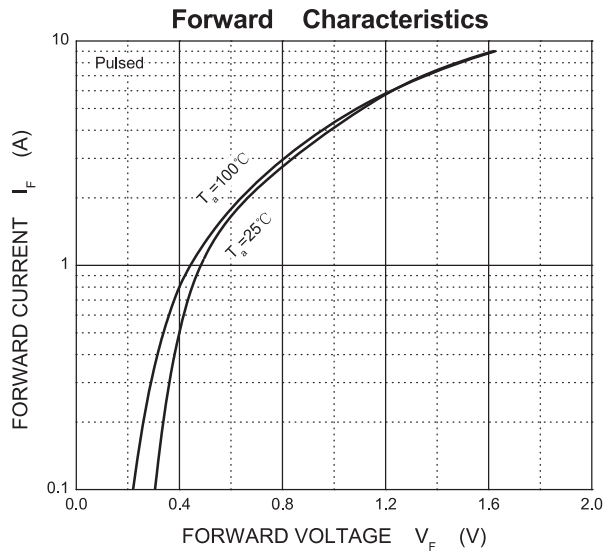


Capacitance Characteristics



Power Derating Curve





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